# Facility Overview Report : Detector Status at PAL-XFEL

**IFDEPS VT** 

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# **PAL-XFEL Overview**

| Injector Accelerator & Distributor       | Undulator Hall                      | Optics Hutch   |
|--|-------------------------------------|--|
|  |                                     | XSS NCI   FXS/FXL CXI/SFX  |
| Fast kicker                              | RSXS XAS/XES                        | X-ray Scattering & Spectroscopy (XSS)<br>Nano Crystallography & Coherent Imaging (NCI)<br>Soft X-ray Scattering & Spectroscopy (SSS) |
|  | Hard X-ray                          | Soft X-ray   |
| Photon energy                            | <b>2.0 ~ 15 keV</b> (0.6 ~ 0.08 nm) | <b>250 ~ 1250 eV</b> (5 ~ 1 nm)  |
| Electron beam energy                     | 4 ~ 11 GeV                          | 3 GeV  |
| Wavelength tuning                        | electron energy                     | gap  |
| Repetition rate                          | 10 Hz, 30 Hz, 60 Hz                 | 10 Hz, 30 Hz, 60 Hz  |
| Band width of pink beam ( $\Delta E/E$ ) | ~ 0.4 %                             | ~ 0.5 %  |
| Photon flux (pink beam)                  | > 1.0 × 10 <sup>11</sup> phs/pulse  | > 1.0 × 10 <sup>12</sup> phs/pulse @ 800eV   |



#### Requirements

From single photon to about 10<sup>4</sup> photons within 100 fs



- Integrating method
- Wide dynamic range
- Low noise & high Q.E.

Large data amount with high frame rate (60 Hz)



- Fast data transfer rate
- Multi-port readout system





Critical issue of life time of the sensor ; Radiation hardness



**Geometrical restriction** ; Pixel and detector sizes, distance between sample to detector, and so on



Science goals and samples

## **Strategy for Detector Introduction**





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# **Detectors for HX Beamline**

+ PD, APD





## **Applications of HX Detectors**



Detectors with more complex configurations are used in most experiments



## **Detectors for SX Beamline**

 Avalanche photo-diode (APD) and microchannel plate
(MCP) are mainly used for most scientific
experiments at SX
beamline



|               | Newton DO940P-BN   | PI-MTE 2048B                                       | PERCIVAL                                    |
|---------------|--|--|---|
| Detector      |  |  |   |
| Energy Range  | 20 eV ~ 10 keV   | 30 eV ~ 10 keV                                     | 250 eV ~ 1 keV                              |
| Pixel Size    | 13.5 $\mu m \times$ 13.5 $\mu m$                             | 13.5 $\mu m \times$ 13.5 $\mu m$                   | $27.0~\mu m \times 27.0~\mu m$              |
| Pixel Number  | 2048 × 512   | $2048\times2048$                                   | 1408 	imes 1484                             |
| Active Area   | 27.6 mm × 6.9 mm   | 27.6 mm × 27.6 mm                                  | 38 mm × 40 mm<br>Sensor size: 45 mm × 50 mm |
| Frame Rate    | 2.48 Hz (1x1)<br>@ 3 MHz readout speed                       | 0.4 Hz (1x1) 1.6 Hz (4x4)<br>@ 2 MHz readout speed | 300 Hz                                      |
| Dynamic Range | ~ 13000<br>@ 3 MHz & sensitivity mode<br>(Full well / noise) | ~ 8000<br>@ 2 MHz readout<br>(Full well / noise)   | $1 \sim 10^5$ photons/pixel @ 250 eV        |
| Status        | Operation for RIXS   | Under commissioning for FTH                        | Under development                           |



#### **R&D : Development of PIN Photo-Diode**

- The R&D for the development of PIN photo-diode started at the end of 2019
  - Collaboration with Kyungpook National University (KNU, Daegu) and Electronics and Telecommunications Research Institute (ETRI, Daejeon)
- First three wafers were fabricated in 2020
  - N-type silicon wafer with a 6-in. diameter, 500  $\mu$ m-thick, high resistivity (>5 k $\Omega$ ·cm), and (100)-orientation used
- Characterizations are ongoing
  - Up to now, the performance of the manufactured photo-diode is comparable with commercial one
  - There is no big issue at the fabrication parameters
- Next fabrication will be followed soon





#### **Future Outlook**

- Most detectors are well established at PAL-XFEL
- Large amount of data is created  $\rightarrow$  The expansion of **data storage server** is being prepared
- JUNGFRAU 16M (in air type) will be delivered by end of 2021, and it will be available for SFX and FXL experiments in the 2nd half of 2022
- PERCIVAL 2M
  - DAQ integration works is ongoing by using FSI detector head
  - BSI will be used for RSXS and FTH experiments
- R&D of the photo-diode will spread to variety branches over long period





#### **BACKUP SLIDES**

#### **Operation Statistics of PAL-XFEL**



<sup>1)</sup> Subject to change depending on the allocation situation in the second half of the year

#### No. of proposals (No. of shifts supported) (2017 ~ 2020)



<sup>2)</sup> 2019-2nd ~ 2021-1st not provided (equipment repair)

<sup>3)</sup> Start of operation in 2020

